

AC Thyristor power switch Rev. 02 — 27 December 2010

Product data sheet

1. **Product profile**

1.1 General description

AC Thyristor power switch in a SOT223 surface-mountable plastic package with self-protective capabilities against low and high energy transients

1.2 Features and benefits

- Common terminal on mounting base allows multiple ACTs on shared cooling pad
- Exclusive negative gate triggering
- Full cycle AC conduction
- High noise immunity
- Remote gate separates the gate driver from the effects of the load current

1.3 Applications

- Fan motor circuits
- Lower-power highly inductive, resistive and safety loads

1.4 Quick reference data

Quick reference data Table 1

- Safe clamping of low energy over-voltage transients
- Self-protective turn-on during high energy voltage transients
- Surface-mountable package
- Very sensitive gate for lowest gate trigger current
- Pump motor circuits

Table 1.	Quick reference d	ata				
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V _{DRM}	repetitive peak off-state voltage		-	-	600	V
I _{GT}	gate trigger current	$V_D = 12 \text{ V}; I_T = 100 \text{ mA}; \text{ LD-} G-; T_j = 25 ^{\circ}C$	0.5	-	5	mA
		$V_D = 12 \text{ V}; I_T = 100 \text{ mA}; \text{LD+} G-; T_j = 25 ^{\circ}C; \text{ see } Figure 10$	0.5	-	5	mA
I _{T(RMS)}	RMS on-state current	full sine wave; T _{sp} ≤ 112 ℃; see <u>Figure 4</u> ; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	-	0.8	A
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T_j = 125 °C; gate open circuit; exponential waveform; see Figure 14	300	-	-	V/µs



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Table 1.	Quick reference da	itacontinued					
Symbol	Parameter	Conditions	Ν	/lin	Тур	Max	Unit
V _{CL}	clamping voltage	I_{CL} = 100 µA; t_p = 1 ms; $T_j \le 125$ °C; see <u>Figure 17</u>	6	650	-	-	V
V _{PP}	peak pulse voltage	T _j = 25 ℃; non-repetitive, off-state; see <u>Figure 3</u>	-		-	2	kV
V _T	on-state voltage	I _T = 1.1 A; see <u>Figure 13</u>	-		-	1.3	V

2. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	LD	load		
2	CM	common		
3	G	gate		G – O –
4	СМ	common		CM
			⊟1 ⊟2 ⊟3 SOT223 (SC-73)	001aaj924

3. Ordering information

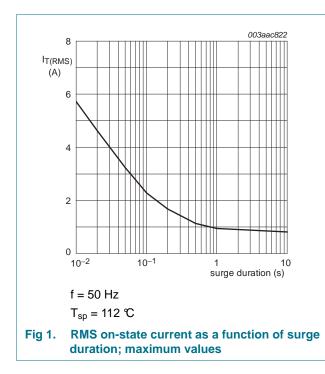
Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
ACT108W-600D	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223			

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	600	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{sp} ≤ 112 ℃; see <u>Figure 4</u> ; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	0.8	А
I _{TSM}	non-repetitive peak on-state current	full sine wave; $T_{j(init)} = 25 \ C$; $t_p = 16.7 \ ms$	-	8.8	А
		full sine wave; $T_{j(init)} = 25 \ C$; $t_p = 20 \ ms$; see <u>Figure 5</u> ; see <u>Figure 6</u>	-	8	А
l ² t	I2t for fusing	t _p = 10 ms; sine-wave pulse	-	0.32	A ² s
dl _T /dt	rate of rise of on-state current	$I_T = 1 \text{ A}; I_G = 10 \text{ mA}; dI_G/dt = 0.2 \text{ A/}\mu\text{s}$	-	50	A/µs
I _{GM}	peak gate current	t = 20 μs	-	1	А
V _{GM}	peak gate voltage	positive applied gate voltage	-	15	V
P _{G(AV)}	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	150	C
Tj	junction temperature		-	125	C
V _{PP}	peak pulse voltage	$T_j = 25 $ °C; non-repetitive, off-state; see Figure 3	-	2	kV



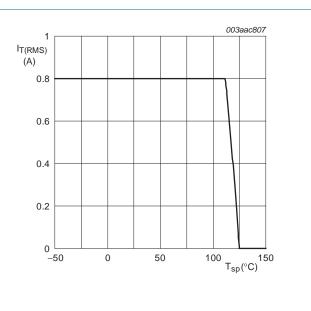
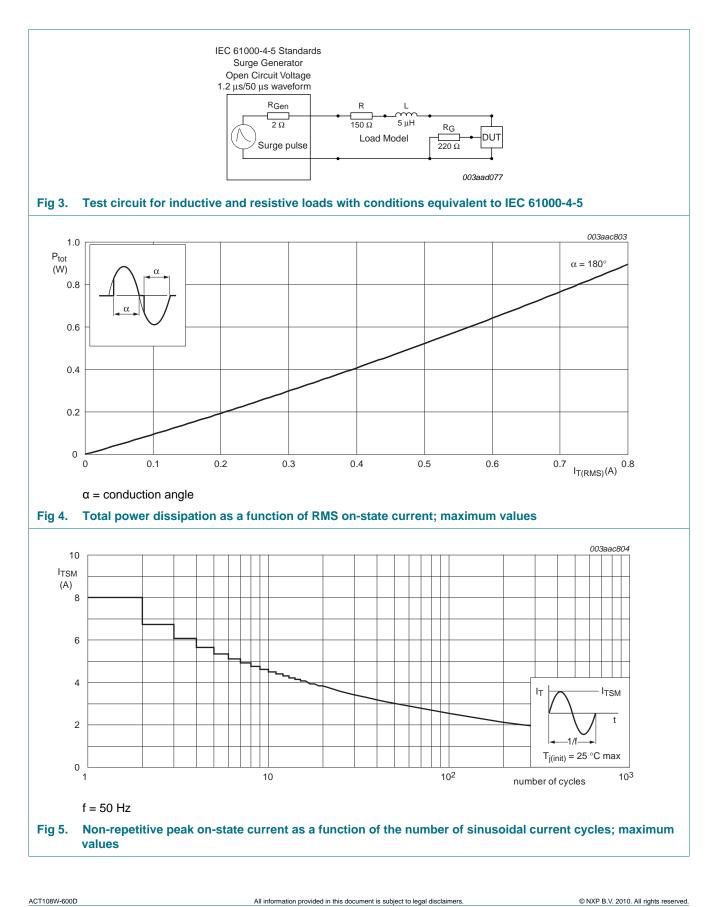


Fig 2. RMS on-state current as a function of solder point temperature; maximum values

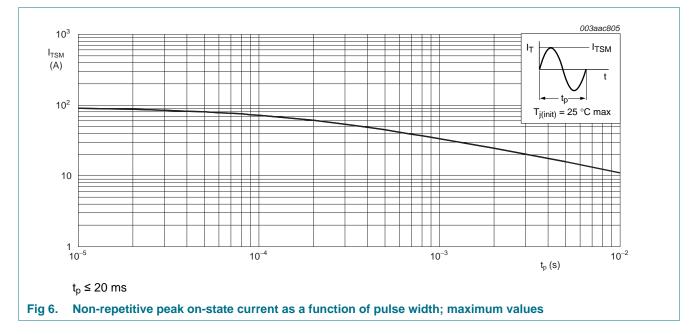
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ACT108W-600D



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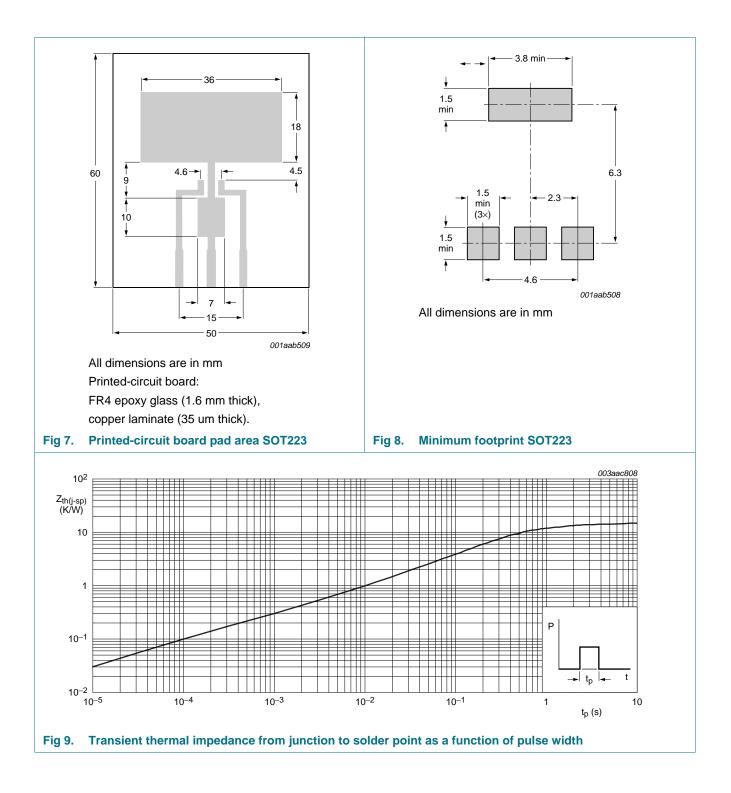


5. Thermal characteristics

Table 5.Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-sp)}	thermal resistance from junction to solder point	full cycle with heatsink compound; see <u>Figure 9</u>	-	-	15	K/W
un() α)	thermal resistance from junction to ambient	full cycle; printed-circuit board mounted for pad area; see Figure 7	-	70	-	K/W
		full cycle; printed-circuit board mounted for minimum footprint; see Figure 8	-	156	-	K/W

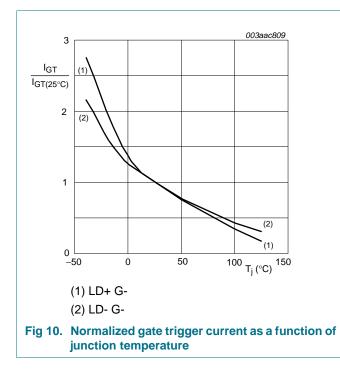
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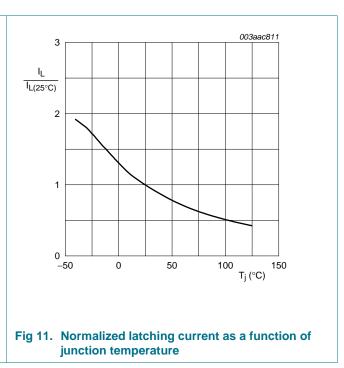


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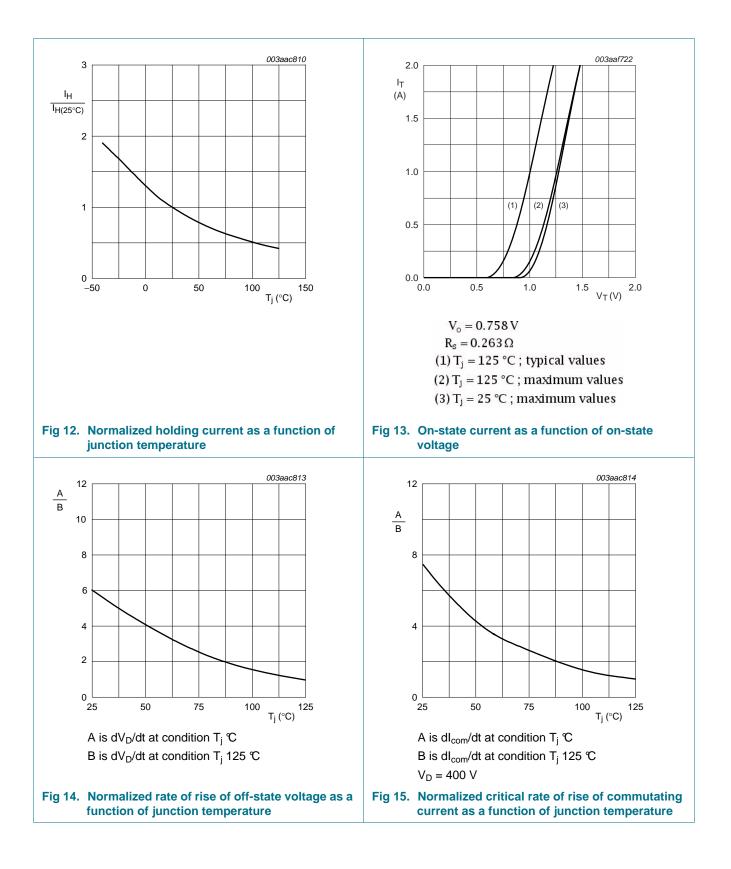
6. Characteristics

Table 6.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{GT}	gate trigger current	$V_D = 12 \text{ V}; \text{ I}_T = 100 \text{ mA}; \text{ LD- G-};$ $T_j = 25 \text{ C}$	0.5	-	5	mA
		V _D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 ℃; see <u>Figure 10</u>	0.5	-	5	mA
۱ _L	latching current	V _D = 12 V; I _G = 12 mA; T _j = 25 °C; see <u>Figure 11</u>	-	-	25	mA
I _H	holding current	$V_D = 12 \text{ V}; \text{ T}_j = 25 ^{\circ}\text{C}; \text{ see } \text{Figure } 12$	-	-	20	mA
VT	on-state voltage	I _T = 1.1 A; see <u>Figure 13</u>	-	-	1.3	V
V _{GT}	gate trigger voltage	$V_D = 12 \text{ V}; \text{ I}_T = 100 \text{ mA}; \text{ T}_j = 25 \text{ °C}$	-	-	0.9	V
		V _D = 12 V; I _T = 100 mA; T _j ≤ 125 ℃	0.15	-	-	V
I _D	off-state current	V _D = 600 V; T _j ≤ 25 ℃	-	-	2	μA
		V _D = 600 V; T _j ≤ 125 ℃	-	-	0.2	mA
dV _D /dt	rate of rise of off-state voltage	V _{DM} = 402 V; T _j = 125 ℃; gate open circuit; exponential waveform; see <u>Figure 14</u>	300	-	-	V/µs
dI _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 125 \text{ C}; \text{ I}_{T(RMS)} = 1 \text{ A};$ $dV_{com}/dt = 15 \text{ V}/\mu\text{s};$ gate open circuit; see <u>Figure 15</u> ; see <u>Figure 16</u>	0.15	-	-	A/ms
V _{CL}	clamping voltage	I _{CL} = 100 μA; t _p = 1 ms; T _j ≤ 125 ℃; see <u>Figure 17</u>	650	-	-	V

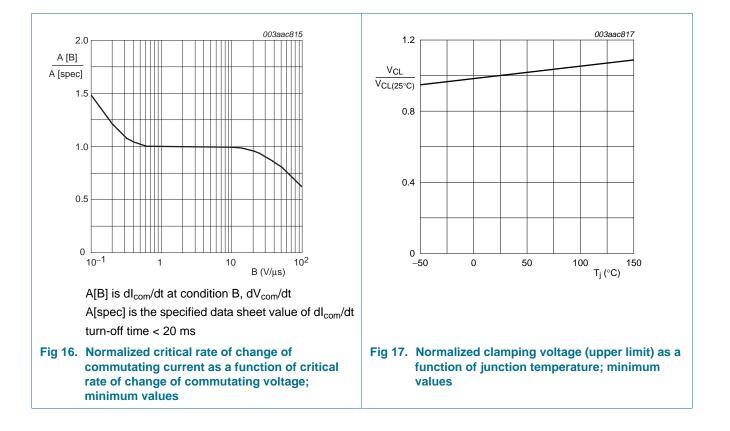




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7. Package outline

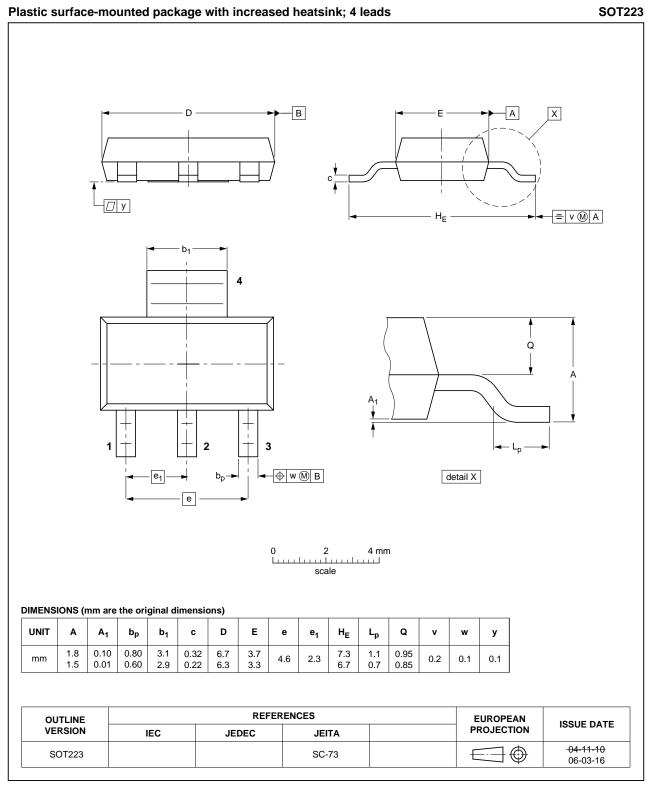
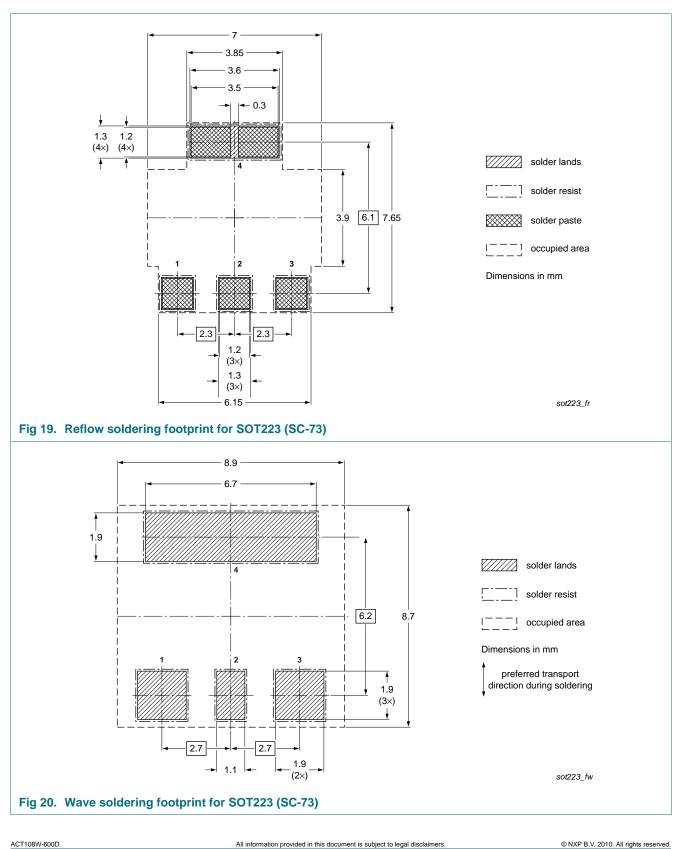


Fig 18. Package outline SOT223 (SC-73)

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Soldering 8.





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9. Revision history

Table 7. Revision l	nistory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
ACT108W-600D v.2	20101227	Product data sheet	-	ACT108W-600D v.1
Modifications:	 Status changed 	d from Preliminary to Produc	ot.	
	 Various change 	es to content.		
ACT108W-600D v.1	20100902	Preliminary data shee	t -	-

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Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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